# EA5070FA16-22.5792M



#### EA5070 F A 16 -22.5792M

Series Quartz Crystal Resonator 5.0mm x 7.0mm x 1.3mm 4 Pad Ceramic Surface Mount (SMD)

L Nominal Frequency 22.5792MHz Load Capacitance

16pF Parallel Resonant

Mode of Operation AT-Cut Fundamental

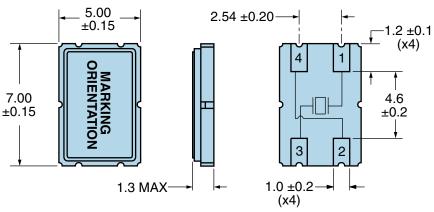
Frequency Tolerance/Stability ±30ppm at 25°C, ±50ppm over -40°C to +85°C

#### **ELECTRICAL SPECIFICATIONS** Nominal Frequency 22.5792MHz Frequency Tolerance/Stability ±30ppm at 25°C, ±50ppm over -40°C to +85°C Aging at 25°C ±3ppm/year Maximum Load Capacitance 16pF Parallel Resonant **Shunt Capacitance** 7pF Maximum **Equivalent Series Resistance** 30 Ohms Maximum Mode of Operation **AT-Cut Fundamental Drive Level** 50uWatts Maximum -3dB Minimum (Measured from Fo to Fo +5000ppm) Spurious Response Storage Temperature Range -40°C to +85°C Insulation Resistance 500 Megaohms Minimum (Measured at 100Vdc) ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

LINVIKONMENTAL & MECHANICAL SPECIFICATIONS		
MIL-STD-883, Method 3015, Class 1, HBM: 1500V		
MIL-STD-883, Method 1014, Condition A		
UL94-V0		
MIL-STD-883, Method 1014, Condition C		
MIL-STD-883, Method 2002, Condition B		
MIL-STD-883, Method 1004		
J-STD-020, MSL 1		
MIL-STD-202, Method 210, Condition K		
MIL-STD-202, Method 215		
MIL-STD-883, Method 2003		
MIL-STD-883, Method 1010, Condition B		
MIL-STD-883, Method 2007, Condition A		

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### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**

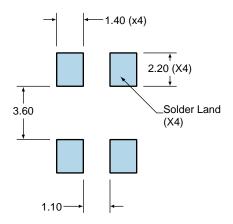


Note: Chamfer and index mark not shown.

PIN	CONNECTION	
1	Crystal	
2	Cover/Ground	
3	Crystal	
4	Cover/Ground	
LINE MARKING		
1	<b>E22.57</b> <i>E=Ecliptek Designator</i>	
2	XXXXX XXXXX=Ecliptek Manufacturing Identifier	

### Suggested Solder Pad Layout

All Dimensions in Millimeters



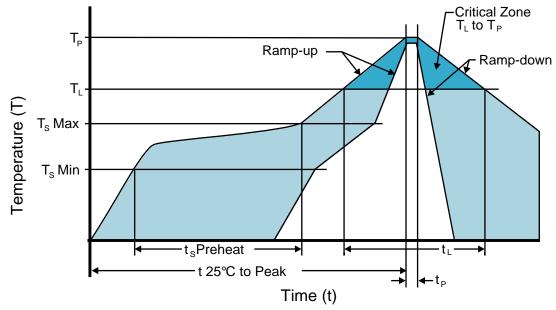
All Tolerances are ±0.1





# **Recommended Solder Reflow Methods**

EA5070FA16-22.5792M



### **High Temperature Infrared/Convection**

T₅ MAX to T∟ (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	150°C
<ul> <li>Temperature Typical (Ts TYP)</li> </ul>	175°C
<ul> <li>Temperature Maximum (Ts MAX)</li> </ul>	200°C
- Time (ts MIN)	60 - 180 Seconds
Ramp-up Rate (T⊾ to T <sub>P</sub> )	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T <sub>P</sub> )	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T <sub>P</sub> Target)	250°C +0/-5°C
Time within 5°C of actual peak ( $t_P$ )	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1
Additional Notes	Temperatures shown are applied to body of device.



# **Recommended Solder Reflow Methods**

EA5070FA16-22.5792M



### Low Temperature Infrared/Convection 245°C

T₅ MAX to T∟ (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	N/A
- Temperature Typical (Ts TYP)	150°C
- Temperature Maximum (Ts MAX)	N/A
- Time (ts MIN)	30 - 60 Seconds
Ramp-up Rate (T⊾ to Tթ)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T <sub>P</sub> )	245°C Maximum
Target Peak Temperature (TP Target)	245°C Maximum 2 Times / 230°C Maximum 1 Time
Time within 5°C of actual peak (t <sub>P</sub> )	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1
Additional Notes	Temperatures shown are applied to body of device.

#### Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)

#### High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)